# FACULTY OF ENGINEERING

## BE II Semester (Main & Backlog) Examination May/June 2018

#### Subject : Engineering Physics-II

Time : 3 Hours.

Max. Marks: 70

## Note : Answer all questions from Part-A & any five questions from Part-B.

#### PART-A (20 Marks)

- 1 Find the Miller indices of a set of parallel lines which make equal intercepts along the three Axes.
- 2 Write short note on crystal imperfections.
- 3 Write any four assumptions of free electron theory.
- 4 The intrinsic carrier density is  $1.5 \times 10^{16}$ /m<sup>-3</sup> if the electron and hole motilities are 0.13 and  $0.05m^2 V^{-1}s^{-1}$  calculate the electrical conductivity.
- 5 What is Meissner effect in superconductors.
- 6 Mention the applications of Ferro electric material.
- 7 What is the significance of Hall effect.
- 8 Distinguish between a dielectric material and an insulator.
- 9 What are the advantages of thin films over bulk materials.
- 10 What is the surface to volume ratio at nano-scale.

# PART-B (5x10=50 Marks)

11.	<ul> <li>a)Discuss the determination of lattice constants by powder diffraction method.</li> <li>b)Distinguish between insulator, semiconductor and conductors based on the energy band diagram.</li> </ul>	6 4
12.	<ul><li>a) Explain the hysteresis curve of a ferro magnetic materials on the basis of magnetic domains.</li><li>b) State the Joshepson effect. Explain the properties of superconducting materials.</li></ul>	5 5
13.	a)What is Hall effect? Obtain the expression for Hall coefficient. b)Explain the crystal structure of the Barium Titanate.	5 5
14.	<ul> <li>a)Explain the principle and the technique of X-ray fluorescence.</li> <li>b)Describe any one type of thermal evaporation technique with neat diagram.</li> </ul>	5 5
15.	a)Explain the synthesis of nano particles using Sol Gel method. b)Write the applications of nano particles.	6 4
16.	a)Explain the frequency and temperature dependence of dielectric polarization. b)What are the salient feature of kronig-Penny model?	6 4
17.	a)Obtain an expression for the conductivity of an n-type semiconductor. b)Explain construction and working of Scanning Electron Microscope(SEM).	5 5